

P.O. Box 747
Falls Church, Virginia 22040-0747
Phone: (703) 205-8000
Fax: (703) 205-8050
(703) 698-8590 (GIV)

Birch, Stewart, Kolasch & Birch, LLP

Fax

To: Examiner David Vu
USPTO
Group 2818

From: Michael K. Mutter

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TECHNOLOGY CENTER 2800

Fax: 703-872-9319

Date: February 25, 2002

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Pages: 17 (including cover sheet)

Your Ref.: SN 09/720,329

Our Ref.: 3672-110P

Re: Response to After
Final Office Action

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Comments:

Please hand-deliver the attached
Response to David Vu.

Thank you.

BOX AF
REPLY UNDER 37 C.F.R. § 1.116
EXPEDITED PROCEDURE
EXAMINING GROUP 2818

PATENT
3672-0110P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: Lucimara S. ROMAN et al. Conf.: 9297
Appl. No.: 09/720,329 Group: 2818
Filed: February 6, 2001 Examiner: VU, DAVID
For: A METHOD IN FABRICATION OF ORGANIC THIN-FILM
SEMICONDUCTING SERVICES

LARGE ENTITY TRANSMITTAL FORM
FOR REPLY AFTER FINAL UNDER 37 C.F.R. § 1.116

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TECHNOLOGY CENTER 2800

BOX AF
Assistant Commissioner for Patents
Washington, DC 20231

February 25, 2002

Sir:

Transmitted herewith is an amendment in the above-identified application.

- ☐ The enclosed document is being transmitted via the Certificate of Mailing provisions of 37 C.F.R. § 1.8.
- ☒ The enclosed document is being transmitted via facsimile.

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INDEPENDEN	2	-	3	=	0	\$ 84	\$0.00
<input type="checkbox"/> FIRST PRESENTATION OF A MULTIPLE DEPENDENT CLAIM						\$280	\$0.00
						TOTAL	\$0.00

Appl. No. 09/720,329

- ☐ Petition for () month(s) extension of time pursuant to 37 C.F.R. §§ 1.17 and 1.136(a). \$0.00 for the extension of time.
- ☒ No fee is required.
- ☐ Check(s) in the amount of \$0.00 is(are) enclosed.
- ☐ Please charge Deposit Account No. 02-2448 in the amount of \$0.00. This form is submitted in triplicate.

If necessary, the Commissioner is hereby authorized in this, concurrent, and future replies, to charge payment or credit any overpayment to Deposit Account No. 02-2448 for any additional fees required under 37 C.F.R. §§1.16 or 1.17; particularly, extension of time fees.

Respectfully submitted,

BIRCH, STEWART, KOLASCH & BIRCH, LLP

By


Michael K. Mutter, #29,680MKM/gf
3672-0110PP.O. Box 747
Falls Church, VA 22040-0747
(703) 205-8000

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RESPONSE UNDER 37 C.F.R. § 1.116
EXPEDITED PROCEDURE
EXAMINING GROUP 2818PATENT
3672-0110P

IN THE U. S. PATENT AND TRADEMARK OFFICE

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APPLICANTS:	Lucimara S. ROMAN et al.	CONF.:	9297
APPLN. NO.:	09/720,329	GROUP:	2818
FILED:	February 6, 2001	EXAMINER:	VU, David
FOR:	A METHOD IN FABRICATION OF ORGANIC THIN-FILM SEMICONDUCTING SERVICES		

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FEB 25 2002AMENDMENT UNDER 37 C.F.R. § 1.116

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BOX AF
Assistant Commissioner for Patents
Washington, D.C. 20231

February 25, 2002

Sir:

Responsive to the Examiner's Office Action dated November 23, 2001, the following amendments and Remarks are respectfully submitted in connection with the above-identified application.

IN THE CLAIMS:

Sub A17
C1

1. (Amended) A method in the fabrication of an electrode structure for an organic thin-film semiconducting device, wherein the semiconducting device is a rectifying diode with a high rectification ratio of an organic thin-film transistor or a hybrid organic/inorganic thin-film transistor comprises